

1-Line Ultra Low Capacitance Bi-directional TVS Diode

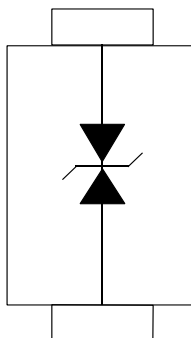
Description

The PESDR0521D5 is a bi-directional TVS diode, to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The PESDR0521D5 has an ultra-low capacitance with a typical value at 0.6pF, and complies with the IEC61000-4-2 (ESD) standard with ±15kV air and ±8kV contact discharge. It is assembled into a SOD-523 lead-free package. The small size ultra- low capacitance and high ESD protection make PESDR0521D5 an ideal choice to protect cell phone, digital video interfaces and other high speed ports.

Features

- Ultra low capacitance: 0.6pF typical
- Ultra low operating voltage: 5V
- Low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
Air discharge: ±15kV
Contact discharge: ±8kV
 - IEC61000-4-5 (Lightning) 3A (8/20µs)
- RoHS Compliant

Dimensions and Pin Configuration



Circuit and Pin Schematic

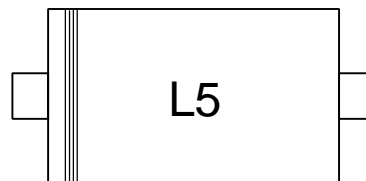
Mechanical Characteristics

- Package: SOD-523
- Lead Finish: Matte Tin
- Case Material: “Green” Molding Compound.
- Moisture Sensitivity: Level 1 per J-STD-020
- Marking Information: See Below

Applications

- Cellular Handsets and Accessories
- Display Ports
- MDDI Ports
- USB Ports
- Digital Video Interface (DVI)
- PCI Express and Serial SATA Ports

Marking Information



L5 = device marking code

Ordering Information

Part Number	Shipping	Reel Size
PESDR0521D5	3000/Tape & Reel	7 inch

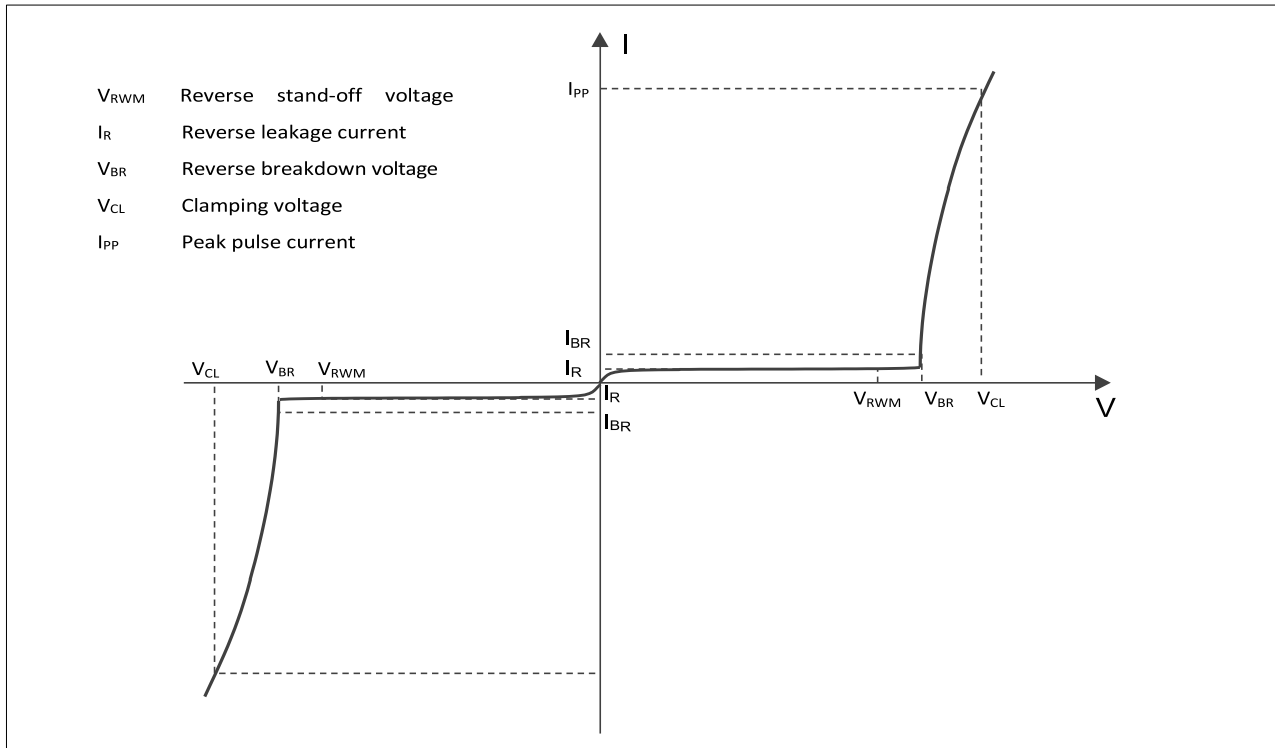
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	P _{PK}	45	W
Peak Pulse Current (8/20μs)	I _{PP}	3	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±15	kV
ESD per IEC 61000-4-2 (Contact)		±8	
Lead temperature	T _L	260	°C
Operating Temperature Range	T _{OP}	-40 ~ +85	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

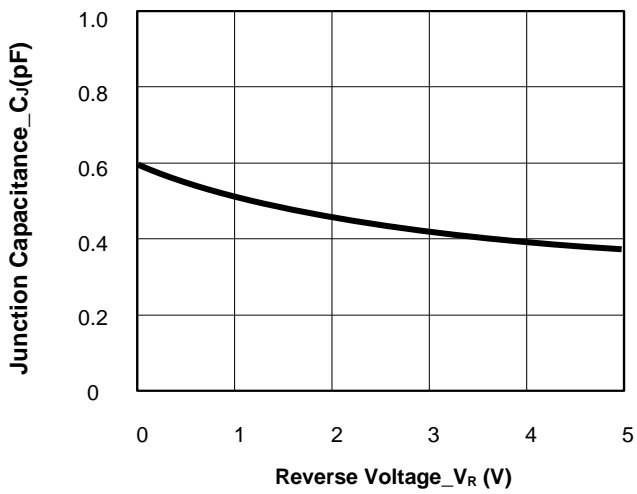
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			5.0	V	
Breakdown Voltage	V _{BR}	6.5			V	I _T = 1mA
Reverse Leakage Current	I _R			100	nA	V _{RWM} = 5V
Clamping Voltage	V _C			15	V	I _{PP} = 3A (8/20μs pulse)
Junction Capacitance	C _J		0.6	0.8	pF	V _R = 0V, f = 1MHz, between I/O pins

Electrical characteristics ($T_A = 25^\circ\text{C}$, unless otherwise noted)

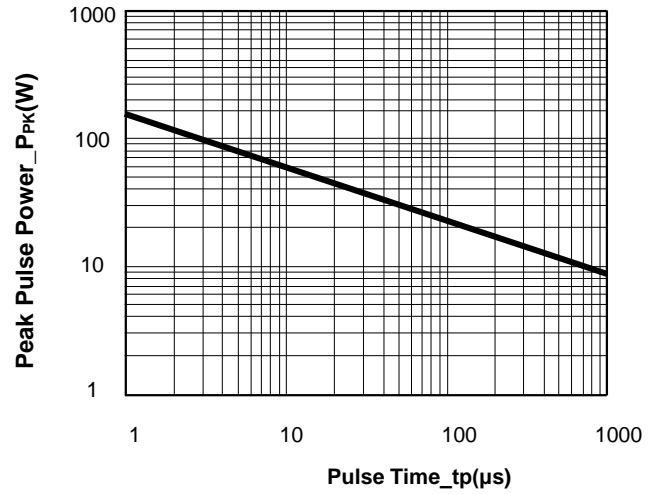


Definitions of electrical characteristics

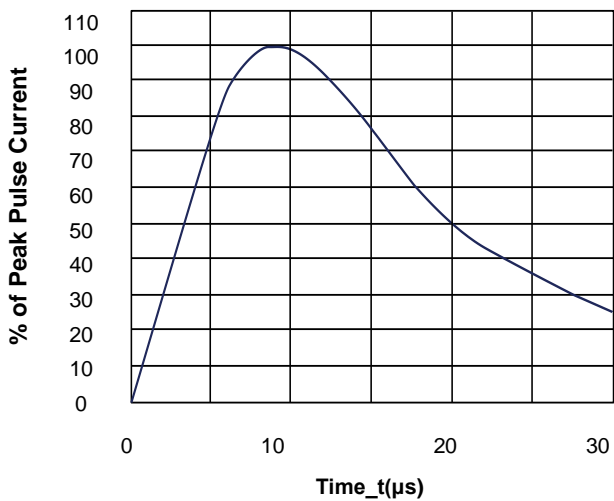
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



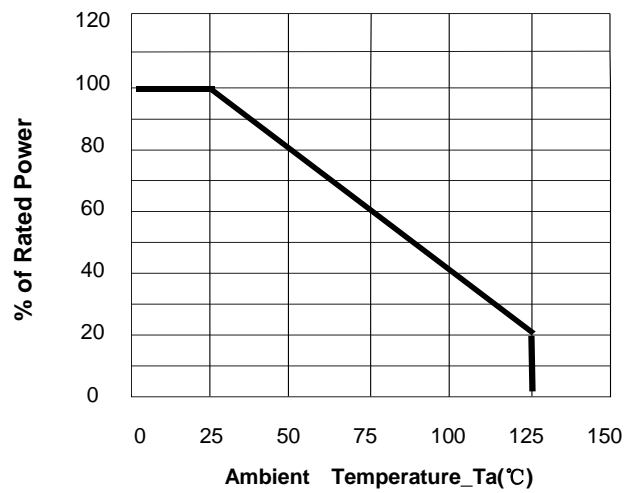
Junction Capacitance vs. Reverse Voltage



Peak Pulse Power vs. Pulse Time

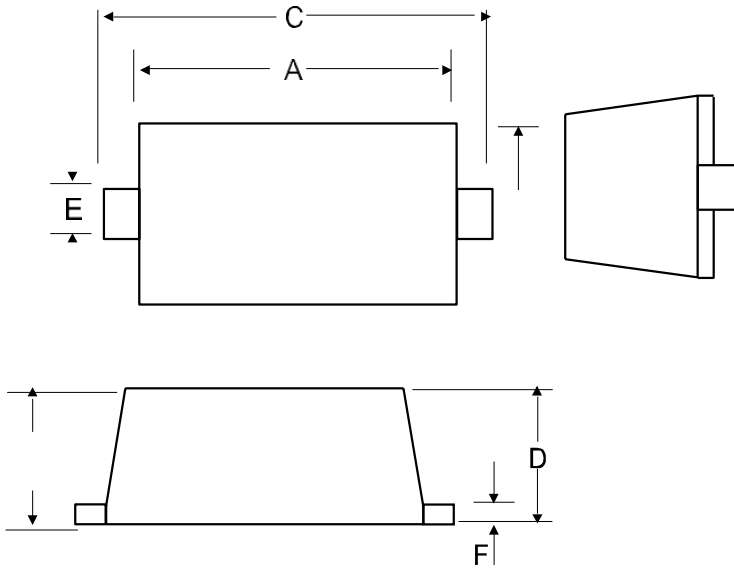


8/20μs Pulse Waveform



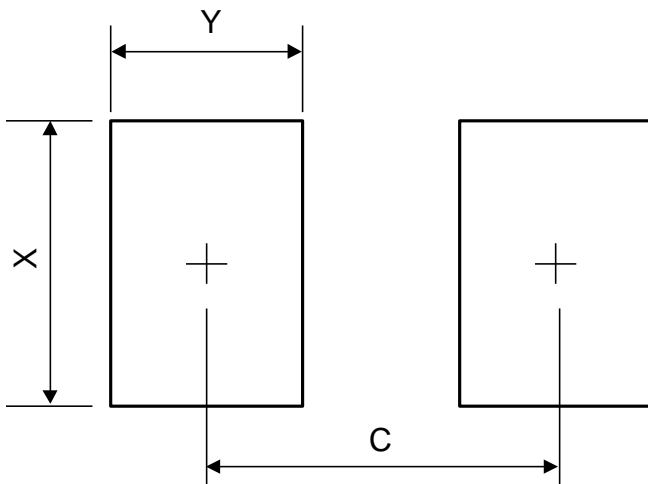
Power Derating Curve

SOD523 Package Outline Drawing



SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.10	1.30	0.043	0.051
B	0.70	0.90	0.028	0.035
C	1.50	1.70	0.059	0.067
D	0.50	0.70	0.020	0.028
E	0.25	0.35	0.010	0.014
F	0.10	0.20	0.004	0.008
G	0.50	0.70	0.020	0.028

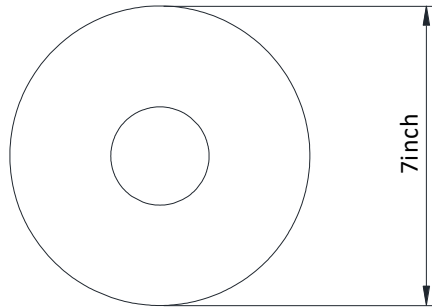
Suggested Land Pattern



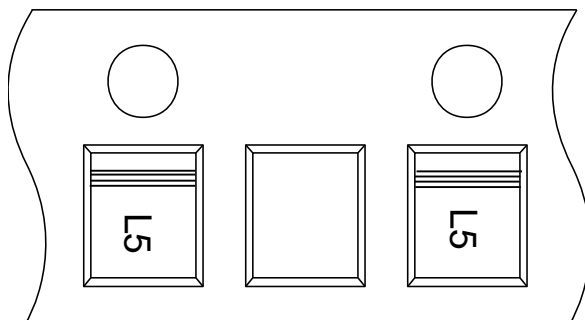
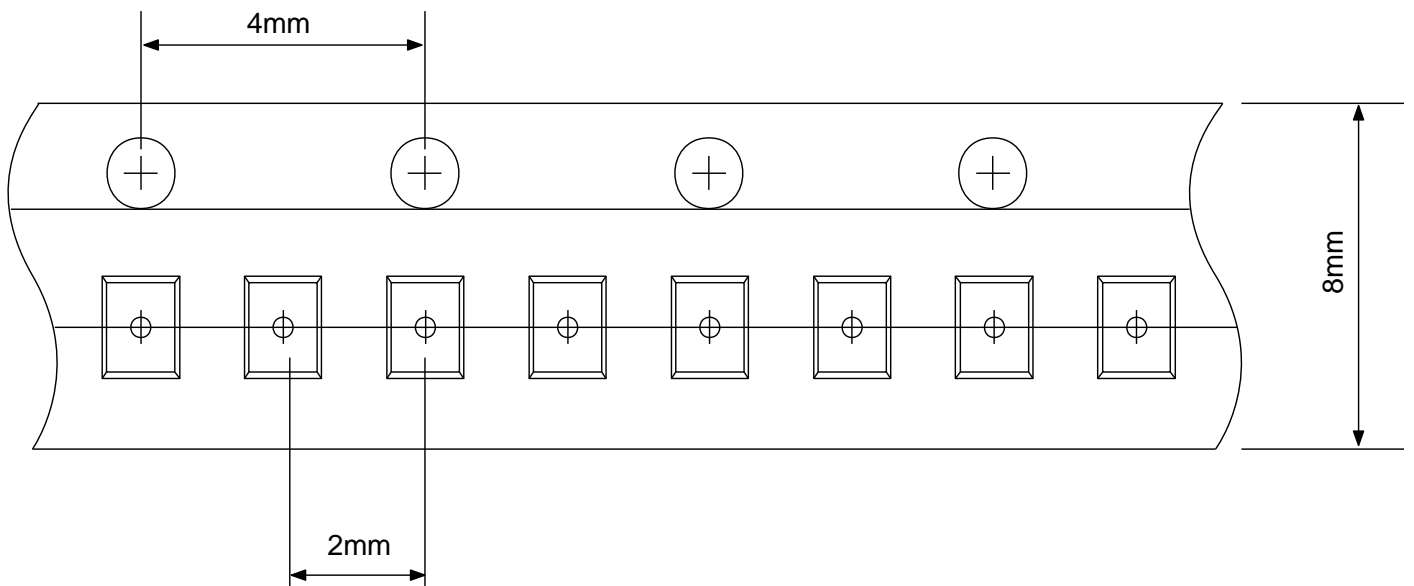
SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	1.42	0.056
X	0.70	0.028
Y	0.60	0.024

TAPE AND REEL INFORMATION

Reel Dimensions



Tape Dimensions




User Direction of Feed

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